# <u>TOSHIBA</u>

TOSHIBA Photocoupler GaAs Ired & Photo-MOS FET / Photo-Transistor



TLP270D

Mobile / Note PCs PDAs Multimedia TVs Modems

TLP270D has many multi-functions in DAA circuits for modems, which is a fully integrated design photocoupler in a 14pin(SOP16).

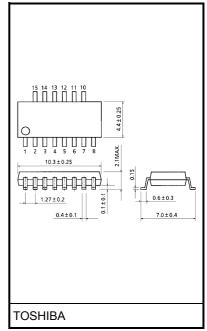
(1) Photorelay

Dial pulsing switch, hookswitch

- 1 form A
- Peak off-state voltage: 200V (min.)
- Trigger LED current: 3mA (max.)
- On-state current: 150mA (max.)
- (2) Photocoupler
  - Ring detection
- Collector-emitter voltage: 80V (min.)
- Current transfer ratio: 50% (min.)

(3) Darlington transistor Electronic inductor

- Collector-emitter voltage: 30V (min.)
- Collector current: 150mA (max.)





Unit in mm

## TOSHIBA

(4) Bridge rectifier

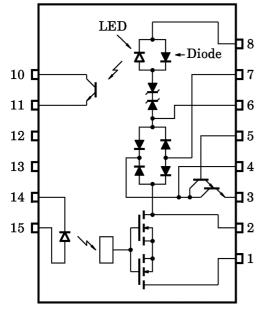
Polarity protection

- Reverse voltage: 30V (min.)
- Forward voltage: 1.7V (max.)
- (5) Zener diode Ring detection protector
- Zener voltage: 22~32V

#### (Common)

- Isolation voltage: 1500Vrms (min.)
- UL recognized: UL1577, file No. E67349

## Pin Configuration (top view)



- 1 : MOSFET Drain
- 2 : MOSFET Drain/Bridge Rectifier Input
- 3 : Darlington Emitter
- 4 : Darlington Collector/Bridge Rectifier Output
- 5 : Darlington Base
- 6 : Bridge Rectifier Input/LED Anode (Diode Cathode)
- 7 : Bridge Rectifier Input
- 8 : LED Cathode / Diode Anode
- 10 : Photo Tr. Collector
- 11 : Photo Tr. Emitter
- 12 : NC
- 13 : NC
- 14 : LED Cathode
- 15 : LED Anode

#### Photorelay(1-form-A)

#### Maximum Ratings (Ta = 25°C)

|          | Characteristic                                | Symbol                | Rating | Unit    |
|----------|---|-----------------------|--------|---------|
|          | Forward current                               | ١ <sub>F</sub>        | 50     | mA      |
|          | Forward current derating<br>(Ta ≥ 25°C)       | ΔI <sub>F</sub> / °C  | -0.5   | mA / °C |
| LED      | Peak forward current<br>(100μs pulse, 100pps) | IFP                   | 1      | А       |
|          | Reverse voltage                               | V <sub>R</sub>        | 5      | V       |
|          | Junction temperature                          | Tj                    | 125    | °C      |
|          | Off-state output terminal voltage             | V <sub>OFF</sub>      | 200    | V       |
| ctor     | On-state RMS current                          | I <sub>ON</sub>       | 150    | mA      |
| Detector | On–state RMS current<br>derating(Ta ≥ 25°C)   | Δl <sub>ON</sub> / °C | -1.5   | mA / °C |
|          | Junction temperature                          | Tj                    | 125    | °C      |

#### Individual Electrical Characteristics (Ta = 25°C)

|          | Characteristic    | Symbol           | Test Condition         | Min. | Тур. | Max. | Unit |
|----------|-------------------|------------------|------------------------|------|------|------|------|
|          | Forward voltage   | VF               | I <sub>F</sub> =10mA   | 1.0  | 1.15 | 1.3  | V    |
| LED      | Reverse current   | I <sub>R</sub>   | V <sub>R</sub> =5V     | _    | _    | 10   | μA   |
|          | Capacitance       | CT               | V=0, f=1MHz            |      | 30   |      | pF   |
| Detector | Off-state current | IOFF             | V <sub>OFF</sub> =200V | Ι    | Ι    | 1    | μA   |
| Dete     | Capacitance       | C <sub>OFF</sub> | V=0, f=1MHz            |      | 90   |      | pF   |

#### Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic      | Symbol          | Test Condition                              | Min. | Тур. | Max. | Unit |
|---------------------|-----------------|---|------|------|------|------|
| Trigger LED current | I <sub>FT</sub> | I <sub>ON</sub> =150mA                      | _    | 1    | 3    | mA   |
| On-state resistance | R <sub>ON</sub> | I <sub>ON</sub> =150mA, I <sub>F</sub> =5mA | _    | 5    | 8    | Ω    |

## Switching Characteristics (Ta = 25°C)

| Characteristic | Symbol          | Test Condition               | Min. | Тур. | Max. | Unit |
|----------------|-----------------|------------------------------|------|------|------|------|
| Turn-on time   | t <sub>ON</sub> | $R_L=200\Omega, V_{CC}=20V,$ | _    | _    | 1.5  | ms   |
| Turn-off time  | tOFF            | I <sub>F</sub> =5mA          |      | -    | 1    | 1113 |

## Photocoupler (AC-input transistor output)

## Maximum Ratings (Ta = 25°C)

|          | Characteristic  | Symbol               | Rating | Unit    |
|----------|---|----------------------|--------|---------|
|          | Forward current   | ١ <sub>F</sub>       | ±50    | mA      |
| Q        | Forward current derating $(Ta \ge 25^{\circ}C)$             | ΔI <sub>F</sub> / °C | -0.5   | mA / °C |
| LED      | Pulse forward current<br>(100µs pulse,100pps)               | I <sub>FP</sub>      | 1      | А       |
|          | Junction temperature  | Tj                   | 125    | °C      |
|          | Collector-emitter voltage                                   | V <sub>CEO</sub>     | 80     | V       |
|          | Emitter-collector voltage                                   | V <sub>ECO</sub>     | 7      | V       |
| 'n       | Collector current   | Ι <sub>C</sub>       | 50     | mA      |
| Detector | Collector power dissipation (1 circuit)                     | P <sub>C</sub>       | 150    | mW      |
|          | Collector power dissipation derating(Ta ≥ 25°C) (1 circuit) | ΔP <sub>C</sub> /°C  | -1.5   | mW / °C |
|          | Junction temperature  | Тj                   | 125    | °C      |

## Individual Electrical Characteristics (Ta = 25°C)

|          | Characteristic                         | Symbol  | Test Condition                                  | Min.     | Тур.        | Max.        | Unit |
|----------|--|---|---|----------|-------------|-------------|------|
| Q        | Forward voltage                        | V <sub>F</sub>  | I <sub>F</sub> =±10mA                           | 1.0      | 1.15        | 1.3         | V    |
| LED      | Capacitance                            | CT  | V=0, f=1MHz                                     | _        | 60          | _           | pF   |
|          | Collector-emitter<br>breakdown voltage | V <sub>(BR)CEO</sub>  | I <sub>C</sub> =0.5mA                           | 80       | _           | _           | V    |
|          | Emitter–collector<br>breakdown voltage | V <sub>(BR)ECO</sub>  | I <sub>E</sub> =0.1mA                           | 7        | _           | _           | V    |
| Detector | Collector dark current                 | 1-  | V <sub>CE</sub> =48V<br>(ambient light: 100 lx) | _        | 0.01<br>(2) | 0.1<br>(20) | μA   |
|          | Collector dark current I <sub>D</sub>  | V <sub>CE</sub> =48V, T <sub>a</sub> =85°C<br>(ambient light: 100 lx) | _   | 2<br>(4) | 50<br>(50)  | μA          |      |
|          | Capacitance                            | C <sub>CE</sub>   | V=0, f=1MHz                                     | _        | 10          |             | pF   |

## Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic                       | Symbol   | Test Condition                             |  | Min. | Тур. | Max. | Unit |
|--------------------------------------|--|--|--|------|------|------|------|
| Current transfer ratio               | I <sub>C/</sub> I <sub>F</sub>   | I <sub>F</sub> =5mA, V <sub>CE</sub> =5V   | I <sub>F</sub> =5mA, V <sub>CE</sub> =5V |      |      | -    | %    |
| (CTR)                                | iC/ iF   |  | Rank GB                                  | 100  |      |      | 70   |
| Saturated CTR                        | I <sub>C/</sub> I <sub>F</sub> I <sub>F</sub> =1mA, V <sub>CE</sub> =0.4V<br>(sat) Rank GB |  | 60                                       |      | %    |      |      |
| Saturated CTT                        |  |  | Rank GB                                  | 30   | _    | _    | 70   |
|                                      |  | I <sub>C</sub> =2.4mA, I <sub>F</sub> =8mA |  | _    | _    | 0.4  |      |
| Collector–emitter saturation voltage | V <sub>CE(sat)</sub>   | I <sub>C</sub> =0.2mA, I <sub>F</sub> =1mA |  | _    | 0.2  | _    | V    |
| C C                                  |  | -  | Rank GB                                  | _    | _    | 0.4  |      |
| Off-state collector current          | I <sub>C(off)</sub>  | V <sub>F</sub> =0.7V, V <sub>CE</sub> =48V |  | _    | _    | 10   | μA   |

#### Switching Characteristics (Ta = 25°C)

| Characteristic | Symbol           | Test Condition  | Min. | Тур. | Max. | Unit |
|----------------|------------------|---|------|------|------|------|
| Rise time      | tr               | V <sub>CC</sub> =10V, I <sub>C</sub> =2mA,<br>R <sub>L</sub> =100Ω  | —    | 2    | —    |      |
| Fall time      | tf               |   | _    | 3    | _    |      |
| Turn–on time   | t <sub>on</sub>  |   | _    | 3    | _    |      |
| Turn–off time  | t <sub>off</sub> |   | _    | 3    | _    | μS   |
| Turn–on time   | t <sub>ON</sub>  |   | _    | 2    | _    |      |
| Storage time   | ts               | R <sub>L</sub> =1.9kΩ, V <sub>CC</sub> =5V,<br>I <sub>F</sub> =16mA | _    | 25   | _    |      |
| Turn–off time  | tOFF             |   | _    | 40   | —    |      |

## Zener Diode

## Individual Electrical Characteristics (Ta = 25°C)

| Characteristic | Symbol | Test Condition | Min. | Тур. | Max. | Unit |
|----------------|--------|----------------|------|------|------|------|
| Zener voltage  | VZ     | -              | 22   | 27   | 32   | V    |

#### **Darlington Transistor**

#### Maximum Ratings (Ta = 25°C)

| Characteristic              | Symbol           | Rating | Unit |
|-----------------------------|------------------|--------|------|
| Collector-base voltage      | V <sub>CBO</sub> | 30     | V    |
| Collector-emitter voltage   | V <sub>CEO</sub> | 30     | V    |
| Emitter-base voltage        | V <sub>EBO</sub> | 10     | V    |
| Collector current           | Ι <sub>C</sub>   | 0.15   | А    |
| Base current                | Ι <sub>Β</sub>   | 20     | mA   |
| Collector power dissipation | PC               | 350    | mW   |
| Junction temperature        | Тј               | 125    | °C   |

### Individual Electrical Characteristics (Ta = 25°C)

| Cha                            | racteristic     | Symbol               | Test Condition  | Min. | Тур. | Max. | Unit |
|--------------------------------|-----------------|----------------------|---|------|------|------|------|
| Collector off current          | nt              | I <sub>CBO</sub>     | V <sub>CB</sub> =30V, I <sub>E</sub> =0                           | _    | _    | 10   | μA   |
| Emitter off current            |                 | I <sub>EBO</sub>     | V <sub>EB</sub> =10V, I <sub>C</sub> =0                           | _    | _    | 10   | μA   |
| Collector-emitter I<br>voltage | breakdown       | V <sub>(BR)CEO</sub> | I <sub>C</sub> =10mA, I <sub>B</sub> =0                           | 30   | _    | _    | V    |
| DC current gain                | DC current gain |                      | V <sub>CE</sub> =2V, I <sub>C</sub> =150mA                        | 4000 | _    | _    |      |
| Collector-emitter s<br>voltage | saturation      | V <sub>CE(sat)</sub> | I <sub>C</sub> =0.15A, I <sub>B</sub> =1mA                        | _    | _    | 1.5  | V    |
|                                | Turn-on time    | t <sub>on</sub>      | 1 1mA )/ 15)/   | _    | 0.20 | _    |      |
| Switching<br>time              | Storage time    | t <sub>stg</sub>     | I <sub>B</sub> =1mA, V <sub>CC</sub> =15V,<br>R <sub>I</sub> =15Ω | _    | 0.6  | _    | μs   |
|                                | Fall time       | t <sub>f</sub>       | 112-1022  | _    | 0.3  | _    |      |

## **Bridge Rectifier**

### Maximum Ratings (Ta = 25°C)

| Characteristic                          | Symbol           | Rating | Unit |
|---|------------------|--------|------|
| Repetitive peak reverse voltage         | V <sub>RRM</sub> | 30     | V    |
| Average output rectified current        | Ι <sub>Ο</sub>   | 0.15   | А    |
| Peak one cycle surge forward<br>current | IFSM             | 0.5    | А    |
| Junction temperature                    | Tj               | 125    | °C   |

## Individual Electrical Characteristics (Ta = 25°C)

| Characteristic                  | Symbol           | Test Condition          | Min. | Тур. | Max. | Unit |
|---------------------------------|------------------|-------------------------|------|------|------|------|
| Forward voltage                 | V <sub>FM</sub>  | I <sub>FM</sub> =0.12A  | _    | —    | 1.7  | V    |
| Repetitive peak reverse current | I <sub>RRM</sub> | V <sub>RRM</sub> =rated | _    | _    | 10   | μA   |

#### Package (common)

#### Maximum Ratings (Ta = 25°C)

| Characteristic                                       | Symbol           | Rating  | Unit |  |
|--|------------------|---------|------|--|
| Total package power dissipation                      | Ρ <sub>T</sub>   | 650     | mW   |  |
| Storage temperature range                            | T <sub>stg</sub> | -55~100 | °C   |  |
| Operating temperature range                          | T <sub>opr</sub> | -20~85  | °C   |  |
| Lead soldering temperature(10s)                      | T <sub>sol</sub> | 260     | °C   |  |
| Isolation voltage<br>(AC, 1min., R.H.≤ 60%) (Note 1) | BVS              | 1500    | Vrms |  |

(Note 1): Device considered a two-terminal device: Pins1, 2, 3, 4, 5, 6, 7 and 8 shorted together and pins 10, 11, 12, 13, 14 and 15 shorted together.

#### Isolation Characteristics (Ta = 25°C)

| Characteristic              | Symbol         | Test Condition                  | Min.             | Тур.             | Max. | Unit |
|-----------------------------|----------------|---------------------------------|------------------|------------------|------|------|
| Capacitance input to output | CS             | V <sub>S</sub> =0, f=1MHz       | —                | 0.8              | _    | pF   |
| Isolation resistance        | R <sub>S</sub> | V <sub>S</sub> =500V, R.H.≤ 60% | $5\times10^{10}$ | 10 <sup>14</sup> | _    | Ω    |
| Isolation voltage           | BVS            | AC, 1 minute                    | 1500             | -                | _    | Vrms |
|                             |                | AC, 1 second, in oil            | —                | 3000             | _    |      |
|                             |                | DC, 1 minute, in oil            | —                | 3000             | _    | Vdc  |

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